# MACRONIX PRODUCT SELECTION GUIDE

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MACRONIX NAND Flash Ø

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June, 2021



A Leading Non-Volatile Memory Solutions Provider

# Serial NOR Flash

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# MACRONIX Your Trustworthy & Reliable Partner

Macronix, the leading provider of NVM (Non-Volatile Memory) semiconductor solutions, produces an expansive range of NOR Flash, NAND Flash, and ROM products. Macronix continues to deliver high quality, innovative and performance driven products, ideal for diverse applications from computing, consumer, networking, and industrial, to mobile, embedded, automotive, and Internet of Things (IoT).

Macronix is one of the few IDM (Integrated Device Manufacturer) companies worldwide with complete Design, Manufacturing, and Marketing capabilities under its own Brand. Macronix dedicates itself to developing superior homegrown technologies and consistently improving its manufacturing processes in order to offer its customers quality products and services.

#### **Broad Product Portfolio**

Designers can select from a broad array of Serial NOR and Parallel NOR Flash memory solutions, spanning 3V, 1.8V and 1.2V products from 512 Kb to 2Gb and NAND Flash memory solutions from 512Mb to 8Gb. Packaging configurations include single-die packaged, Known Good Die (KGD), wafer, and multi-chip package (MCP) configurations.

#### **Technology Innovator**

Macronix believes that Innovation and Differentiation are key factors in creating a better, more valuable future for our customers and partners. Macronix has been dedicating more than 20% of its annual revenune to Research and Development. We have strong technology portfolio with over 8000 patents.

#### Long-term Commitment and Support

Macronix has over 30 years of IDM experience with excellent in-house design and manufacturing capabilities, which facilitate continuous improvement in all aspects of the development and production cycle. Macronix is committed to providing reliable and efficient support to satisfy customers' expectations for long-lasting partnerships.

#### **Reliable Quality Standard**

Macronix's stringent quality standards, based on the ISO 9001 philosophy, have resulted in TS 16949 certification. Our Green Product Management system is highly regarded in the industry. Macronix has been granted green partnerships with Canon, LG, Nintendo, Sony and Samsung.





# Serial NOR Flash

04

Macronix designs and manufactures 1.8V, 2.5V and 3V Serial NOR Flash products from 512Kb to 2Gb. We also offer backwardcompatible, high-performance Serial NOR Flash, MXSMIO<sup>®</sup> (Multi-I/O) family and MXSMIO<sup>®</sup> Duplex (DTR) family. CRONN

Density	Mode	Organization	I/O Bus	I/O Bus Speed Package (MHz)		Voltage	Temperature Range
MX25	<b>5/66L</b> 3V Serial NO	OR Flash					
2Gb	MXSMIO <sup>®</sup> , DTR	4KB/32KB/64KB	x1,x2,x4	STR:166 DTR:100	24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C
1Gb	MXSMIO®, DTR, Dual Quad	4KB/32KB/64KB	x1,x2,x4	STR:166 DTR:100	16-SOP, 24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
512Mb	MXSMIO <sup>®</sup> , DTR, Dual Quad, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR:166 DTR:100	8-WSON,16-SOP, 24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
256Mb	MXSMIO <sup>®</sup> , DTR, Dual Quad, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR:133 DTR:100	8-SOP/WSON,16-SOP, 24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
128Mb	MXSMIO®, DTR, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR:133 DTR:100	8-SOP/WSON,16-SOP, 24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C
64Mb	MXSMIO®, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	133	8-SOP/WSON, 16-SOP, 24-TFBGA	2.65-3.6V 2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
32Mb	MXSMIO®, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	133	8-SOP/WSON/USON, 16-SOP,24-TFBGA	2.65-3.6V 2.7-3.6V	-40°C to +85°C -40°C to +105°C
16Mb	MXSMIO®, Quad I/O Permanent Enabled	4KB/64KB	x1,x2,x4	133	8-SOP,24-TFBGA	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
8Mb	MXSMIO®	4KB/64KB	x1,x2,x4	133	8-SOP/WSON/USON	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
4Mb	Default Lock Protection	4KB/64KB	x1,x2	86	8-SOP/WSON/USON	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
2Mb	Default Lock Protection	4KB/64KB	x1,x2	86	8-SOP	2.7-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
1Mb	Default Lock Protection	4KB/64KB	x1,x2	104	8-SOP	2.7-3.6V	0°C to +70°C -40°C to +85°C
512Kb	Standard Interface	4KB/64KB	x1,x2	104	8-SOP/TSSOP/USON	2.7-3.6V	0°C to +70°C -40°C to +85°C



Density	Mode	Organization	I/O Bus	Speed (MHz)	Package	Voltage	Temperature Range					
MX25	MX25V 2.5-3V Serial NOR Flash											
16Mb	Multi I/O	4KB/32KB/64KB	x1,x2	104	8-SOP/WSON	2.3-3.6V	-40°C to +85°C -40°C to +125°C					
8Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	108	108 8-SOP/WSON/USON		-40°C to +85°C -40°C to +105°C -40°C to +125°C					
4Mb	Multi I/O	4KB/32KB/64KB	x1,x2	104	8-SOP/VSOP/TSSOP/WSON	2.3-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C					
2Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	80	8-SOP/USON	2.3-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C					
1Mb	Multi I/O	4KB/32KB/64KB	x1,x2	80	8-SOP/TSSOP/USON	2.3-3.6V	-40°C to +85°C -40°C to +105°C -40°C to +125°C					
512Kb	Multi I/O	4KB/32KB/64KB	x1,x2	80	8-SOP/TSSOP/USON	2.3-3.6V	-40°C to +85°C					

Density	Mode	Organization	I/O Bus	Speed (MHz)	Package	Voltage	Temperature Range
MX25	5/66U 1.8	V Serial NOR Flas	sh				
2Gb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR: 166 DTR:100	24-TFBGA	1.65-2.0V	-40°C to +85°C -40°C to +105°C
1Gb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR: 166 DTR:100	16-SOP, 24-TFBGA	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
512Mb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR: 166 DTR:100	8-WSON,16-SOP,24-TFBGA, WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
256Mb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR: 166 DTR:100	8-WSON/8-WLGA,16-SOP, 24-TFBGA, WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
128Mb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	STR: 166 DTR:100	8-SOP/WSON,16-SOP, 24-TFBGA, WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
64Mb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	133	8-SOP/WSON/VSOP/XSON/USON, WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
32Mb	Multi I/O, Quad I/O Permanent Enabled	4KB/32KB/64KB	x1,x2,x4	133	8-SOP/WSON/USON,WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
16Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	133	8-SOP/USON,WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +105°C -40°C to +125°C
8Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	108	8-SOP/WSON/USON,WLCSP	1.65-2.0V	-40°C to +85°C
4Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	108	8-SOP/VSOP/USON,WLCSP	1.65-2.0V	-40°C to +85°C -40°C to +125°C
2Mb	Multi I/O	4KB/32KB/64KB	x1,x2,x4	108	8-SOP/VSOP/WSON/USON,WLCSP	1.65-2.0V	-40°C to +85°C
1Mb	Multi I/O	4KB/64KB	x1,x2,x4	70	8-SOP/TSSOP/USON	1.65-2.0V	-40°C to +85°C
512Kb	Multi I/O	4KB/64KB	x1,x2,x4	70	8-SOP/TSSOP/USON	1.65-2.0V	-40°C to +85°C

#### MX25xxx06 - Standard Serial Interface Series

The MX25xxx06 series provides Standard Serial Interface x1 or x2 I/O [Single I/O or Dual I/O] at a single 3V or 2.5V power-supply voltage. The MX25xxx06E products are offered with 4KB sectors and 64KB blocks.

#### MX25xxx26 - Default Lock Protection Series

The default lock protection series is optimized for Parameter Protection applications. These products utilize the BP volatile protection bits to protect selected boot areas of memory against misuse of programs, and to erase instructions in the protected area.

#### MX25/66xxx32/33/35/36/37/39 - MXSMIO®(Multi-I/O) Series

The MXSMIO<sup>®</sup> Family provides two kinds of Multi-I/O interfaces: the MX25xxx32/35/33/37/39 series, which offers a Multi-in / Multi-out interface, and the MX25xxx36 series, which offers a Single-in / Multi-out interface. Both series are available on Quad I/O operation, which quadruples the read performance of systems for high-end consumer applications.

#### MX25/66xxx43/45/59/83/85/89 - MXSMIO®(Multi-I/O) Duplex (DTR) Series

The MX25xxx43/45/59 series offer Quad I/O interface with DTR (Double Transfer Rate) mode operation, featuring the industry's fastest data transfer rate of up to 800MHz. To extend MXSMIO<sup>®</sup> Duplex family I/O selection, we also provide Dual Quad I/O interface with DTR (Double Transfer Rate) mode operation, MX66xxx85 series, featuring data transfer rate of up to 1600MHz, and MX66xxx83/89 series, featuring 2 CS# and 2 SCLK pins. The MXSMIO<sup>®</sup> Duplex family offers independent block lock protection on the boot sector.

#### MX25xxx72/73 - MXSMIO<sup>®</sup> Series (Quad I/O Permanent Enabled)

The MX25xxx72/73 series provide Multi-I/O default enable solution. The Multi-I/O interface is available without any setting in Flash side, and it provides user more convenient way to experience the Multi-I/O performance.

#### MX25/66xxx50/55/56 - Permanent Lock

The MX25/66xxx50/55/56 series with permanent lock feature provide extreme write protection mechanism. This security feature could permanently set block or sector of a flash to be read only. Our flash memory is available to protect system operation from intentional tampering.



# Ultra Low Power Wide Range Vcc Flash

Macronix MX25R Serial NOR Flash is a family of ultra low power/wide range Vcc memory products, suitable for use in a wide variety of the IoT and other energy conscious applications, such as wearable devices, and mobile devices. The MX25R product family features ultra low power consumption, 60% lower than that of traditional products, and wide range Vcc (1.65-3.6V), enabling extended battery life.

The MX25R Serial NOR Flash family with densities ranging from 512Kb to 64Mb supports the standard Serial NOR Flash memory interface, and provides ultra small product packages such as USON, WLCSP, and KGD (Known Good Die) products for SiP (System in Package) solutions.

Density	Organization	I/O Bus	Speed (MHz)	Voltage	Mode	Package
MX25	<b>R</b> Serial NOR Flas	h				
64Mb	4KB/32KB/64KB	x1, x2, x4	80	1.65-3.6V	Multi I/O	8-SOP/WSON/USON,WLCSP
32Mb	4KB/32KB/64KB	x1, x2, x4	80	1.65-3.6V	Multi I/O	8-SOP/WSON/USON,WLCSP
16Mb	4KB/32KB/64KB	x1, x2, x4	80	1.65-3.6V	Multi I/O	8-SOP/WSON/USON,WLCSP
8Mb	4KB/32KB/64KB	x1, x2, x4	108	1.65-3.6V	Multi I/O	8-SOP/USON, WLCSP
4Mb	4KB/32KB/64KB	x1, x2, x4	108	1.65-3.6V	Multi I/O	8-SOP/WSON/USON,WLCSP
2Mb	4KB/32KB/64KB	x1, x2, x4	108	1.65-3.6V	Multi I/O	8-SOP/TSSOP/USON,WLCSP
1Mb	4KB/32KB/64KB	x1, x2, x4	108	1.65-3.6V	Multi I/O	8-SOP/TSSOP/USON,WLCSP
512Kb	4KB/32KB/64KB	x1, x2, x4	108	1.65-3.6V	Multi I/O	8-SOP/TSSOP/USON,WLCSP



# 1.2V Serial NOR Flash (1.14-1.6 V)

With the demand of low power applications, such as health monitoring, Bluetooth connection, IoT, wearables and mobile Internet devices, system engineers will need memory with reduced supply voltage to simplify their design.

The MX25S Series meets these needs by featuring 1.2V (1.14V-1.6V) and ultra-low power consumption (1.65mA ICC\_active, 0.05uA ICC\_dpd), capable of more than 80% power saving compared to the existing Serial NOR Flash. The MX25S will also effectively extend the battery life.

The MX25S series of products is a Serial NOR Flash memory interface, offered from 8Mb to 64Mb densities, and in small form factor packages, such as USON and WLCSP, or KGD (Known Good Die) that can be used with SiP solution.

Density	Organization	I/O Bus	Speed (MHz)	Vcc	Mode	Packages				
MX25S Serial NOR Flash										
8Mb	4KB/32KB/64KB	x1, x2, x4	120	1.14V-1.6V	Multi I/O	8-SOP/USON				
16Mb	4KB/32KB/64KB	x1, x2, x4	120	1.14V-1.6V	Multi I/O	8-SOP				
64Mb	4KB/32KB/64KB	x1, x2, x4	120	1.14V-1.6V	Multi I/O	8-SOP/XSON, WLCSP				

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# **OctaBus<sup>™</sup>Memory**

The new-generation Macronix OctaBus Memory is a portfolio of extreme speed memory products built on Serial Peripheral Interface (SPI) and command protocol, providing extendable I/O capability. Expanding from current Quad I/O to octaflash (8 I/O) will efficiently broaden our Serial NOR Flash throughput. Macronix OctaBus Memory (8 I/ O) also retains the user interface compatible with the ordinary single I/O Serial NOR Flash, which can sustain users' experience in using Serial NOR Flash with minimum efforts.

The LW/UW series is a multiple bank architecture solution based on ultra-high performance OctaBus interface, which provide simultaneous Read-While-Write capability that allows read access from one memory bank while writing to another memory bank.

The LM/UM series is a solution based on the ultra-high performance Macronix OctaBus interface, which dedicates to raising the product performance with the fastest 250MHz frequency, combining with the brand-new Data Transfer Rate (DTR) feature. The data transfer rate has therefore been increased from existing 100MB/s of Quad I/O Serial NOR Flash to 500MB/s, while the read latency has also been lowered immensely. The improved performance will help system in running eXecute In Place (XIP) on octaflash with more efficiency and shorten the access time in high density, which accelerates overall system performance.

It is an ideal solution for Over-The-Air (OTA) update applications which are becoming more prevalent within Automotive Cockpit solutions.

### **Key Features**

- Support 3V/1.8V operation voltage
- Backward compatible with x1 I/O SPI interface
- Both STR & DTR (Double Transfer Rate) mode support
  New DTR feature for Read, Program and Erase
- operation

### LM/UM Series

• Upto 250MHz clock frequency with both DTR/STR operation

### LW/UW Series

- Multiple bank architecture
- Support Simultaneous Read while Write operations

Density	Organization	I/O Bus	Speed (MHz)	Mode	Package
MX25/	<b>66LM</b> 3V 00	ctaBus Mei	mory		
2Gb	4KB / 64KB	x1, x8	133	Octa I/O, DTR	24-BGA (5x5 ball array)
1Gb	4KB / 64KB	x1, x8	133	Octa I/O, DTR	16-SOP, 24-BGA (5x5 ball array)
512Mb	4KB / 64KB	x1, x8	133	Octa I/O, DTR	16-SOP, 24-BGA (5x5 ball array)
256Mb	4KB / 64KB	x1, x8	133	Octa I/O, DTR	16-SOP, 24-BGA (5x5 ball array)
MX25/	<b>66UM</b> 1.8	/ OctaBus	Memory		
2Gb	4KB / 64KB	x1, x8	200	Octa I/O, DTR	24-BGA (5x5 ball array)
1Gb	4KB / 64KB	x1, x8	200	Octa I/O, DTR	24-BGA (5x5 ball array)
512Mb	4KB / 64KB	x1, x8	250	Octa I/O, DTR	16-SOP, 24-BGA (5x5 ball array), WLCSP
256Mb	4KB / 64KB	x1, x8	200	Octa I/O, DTR	16-SOP, 24-BGA (5x5 ball array), WLCSP
128Mb	4KB/8KB	x1, x8	200	Octa I/O, DTR	16-SOP, 24-BGA(5x5 ball array)

Density	Organization	I/O Bus	Speed (MHz)	Mode	Package						
MX25/	MX25/66LW 3V Read-While-Write OctaBus Memory										
2Gb	4KB/64KB	x1,x8	133	Octa I/O, DTR, Multiple Bank, RWW	24-BGA (5x5 ball array)						
1Gb	4KB/64KB	x1,x8	133	Octa I/O, DTR, Multiple Bank, RWW	24-BGA (5x5 ball array)						
512Mb	4KB/64KB	x1,x8	133	Octa I/O, DTR, Multiple Bank, RWW	16-SOP, 24-BGA (5x5 ball array)						
256Mb	4KB/64KB	x1,x8	133	Octa I/O, DTR, Multiple Bank, RWW	6x8mm 24-TFBGA (5x5)						
MX25	MX25/66UW 3V Read-While-Write OctaBus Memory										
2Gb	4KB/64KB	x1,x8	200	Octa I/O, DTR, Multiple Bank, RWW	24-BGA (5x5 ball array)						
1Gb	4KB/64KB	x1,x8	200	Octa I/O, DTR, Multiple Bank, RWW	24-BGA (5x5 ball array)						
512Mb	4KB/64KB	x1,x8	200	Octa I/O, DTR, Multiple Bank, RWW	16-SOP, 24-BGA (5x5 ball array)						
256Mb	4KB/64KB	X1,X8	200	Octa I/O, DTR, Multiple Bank, RWW	24-BGA (5x5 ball array)						
128Mb	4KB/64KB	x1,x8	200	Octa I/O, DTR, Multiple Bank, RWW	16-SOP, 24-BGA (5x5 ball array), WLCSP						
64Mb	4KB/64KB	x1,x8	200	Octa I/O, DTR, Multiple Bank, RWW	16-SOP, 24-BGA (5x5 ball array), WLCSP						

NAM       250       45       6       M       M       0         PINE:       Pin		OctaBus™	Memory Example	2
DEVICE:       25UM/66UM:         1.8V,8 1/0,Serial NOR Flash       25UM/66UM:         3V,8 1/0, Serial NOR Flash       25UW/66UM:         25UW/66UW:       25UW/66UW:         3V,8 1/0, Read-while-Write Serial NOR Flash       25UW/66UW:         25U/2531: 25MD       3: Byte Mode data output sequence.         512/5131: 212MD       A: with 90 Degree shifted SCLK2.         16 16b       26 : 26b         * Density & Mode:       MODE:         123/23/12A*: 123MD       A: with 90 Degree shifted SCLK2.         16 : 16b       26 : 26b         * Density & Mode:       MODE:         123/23/12A*: 123MD       A: with 90 Degree shifted SCLK2.         123/23/12A*: 123MD       A: with 90 Degree shifted SCLK2.         124/23/12A*: 123MD       A: with 90 Degree shifted SCLK2.         125/2531: 256MD       S: MXSMIO*Duplex(DTR)-Multi-M         26/273: 3253/133/136/2631:       S: MXSMIO*Duplex(DTR)-Multi-M         27/23/23/3353/136/2631:       S: MXSMIO*Duplex(DTR)-Multi-M         27/23/23/3353/136/2631:       S: MXSMIO*Duplex(DTR)-Multi-M <td< th=""><th></th><th>MX 25UM 256 45</th><th>G M I 00</th><th></th></td<>		MX 25UM 256 45	G M I 00	
<ul> <li>25UM/66UM : 1.8V,81/0,Serial NOR Flash 25UW/66UW : 3V,81/0,Read-while-Write Serial NOR Flash 25UW/66UW : 4: 1 CS#, Multi 1/0 Mode Permanent Enabled, Default Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Multi 1/0 Mode Permanent Enabled, Default Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Multi 1/0 Mode Permanent Enabled, Default Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 8 Dummy Cycle 5: 1 CS#, Default 5 Standard 1/0, Default 6 Cot 25°C 1: Industrial (-40°C to 155°C) 5: Automotive Grade 1 (-40°C to 155°C) 5: Automotive Grade 1 (-40°C to 155°C) 5: Automotive Grade 1 (-40°C to 155°C) 5: Automotive Carde 3 (-40°C to 155°C) 5:</li></ul>	DEVICE:			FEATURE CODE 1:
<ul> <li>1.8V, 81/O, Serial NOR Flash</li> <li>2SLW/66LM:</li> <li>3V, 81/O, Serial NOR Flash</li> <li>2SUW/66LW:</li> <li>1.8V, 81/O, Read-while-Write Serial NOR Flash</li> <li>2SUV/66LW:</li> <li>3V, 81/O, Read-while-Write Serial NOR Flash</li> <li>2SUV/351/31/32/23:</li> <li>Byte Mode data</li> <li>WODE:</li> <li>45: MXSMIO* Duplex(DTR)-Multi-in, Multi-out</li> <li>50: MXSMIO* Security RPMC type</li> <li>As with 90 Degree shifted SCLK2</li> <li>63/123/53/131/163/263:</li> <li>Byte Mode data</li> <li>S0: MXSMIO* Security RPMC type</li> <li>Center Addition of the security of t</li></ul>	25UM/66UM		0:10	S#, Default Standard I/O, Default Standard Dummy Cycle
<ul> <li>25LM/66LM:</li> <li>3V, 8 //O, Serial NOR Flash</li> <li>25UW/66UW:</li> <li>1.8V, 8 //O, Read-while-Write Serial NOR Flash</li> <li>25UW/66LW:</li> <li>3V, 8 //O, Read-while-Write Serial NOR Flash</li> <li>25UW/66LW:</li> <li>3V, 8 //O, Read-while-Write Serial NOR Flash</li> <li>256/253*: 256Mb</li> <li>25 12Mb</li> <li>2512Mb</li> <li>25</li></ul>	1.8V,8 I/O,Serial NOR Flash			S#, Multi I/O Modo Pormanont Enabled
<ul> <li>Sty, 8 1/0, Read-while-Write Serial NOR Flash</li> <li>25LW/66LW :</li> <li>3V, 8 1/0, Read-while-Write Serial NOR Flash</li> <li>25LW/66LW :</li> <li>3V, 8 1/0, Read-while-Write Serial NOR Flash</li> <li>DENSITY:</li> <li>64: 64Mb</li> <li>256/253*: 256Mb 3: Byte Mode data output sequence.</li> <li>51/253*: 256Mb 3: Byte Mode data output sequence.</li> <li>51/253*: 512Mb A: with 90 Degree shifted SCLK2.</li> <li>1G: 1Gb</li> <li>2G: 2Gb</li> <li>*Density &amp; Mode:</li> <li>128/123/253/513/1G3/2G3:</li> <li>Byte Mode data</li> <li>WDDE:</li> <li>45: MXSMI0*Duplex(DTR)-Multi-in, Multi-out</li> <li>50: MXSMI0*Security RPMC type</li> <li>GENERATION</li> <li>GENERATION</li> </ul>	25LM/66LM :		4. I C.	ault Standard Dummy Cycle
<ul> <li>1.8W, 8 I/O, Read-while-Write Serial NOR Flash</li> <li>2.5W/66LW:</li> <li>3V, 8 I/O, Read-while-Write Serial NOR Flash</li> <li>2.5W/66LW:</li> <li>3V, 8 I/O, Read-while-Write Serial NOR Flash</li> <li>2.5W/66LW:</li> <li>3V, 8 I/O, Read-while-Write Serial NOR Flash</li> <li>2.5W/561W:</li> <li>2.56/253*: 2.56MD</li> <li>2.56/253*: 2.56MD</li> <li>2.56/253*: 2.56MD</li> <li>2.50MD</li> <li>2.51/513*: 512MD</li> <li>2.50MD</li> <li>2.50MD</li> <li>2.50MD</li> <li>2.50MD</li> <li>2.50MD</li> <li>3.50MD</li> <li>2.50MD</li> <li>3.50MD</li> <li></li></ul>	3V, 8 I/O, Serial NOR Flash		5:10	S#. Multi I/O Mode Permanent Enabled.
25LW/66LW:         3LW/66LW:         3V, 81/O, Read-while-Write Serial NOR Flash         DENSITY:         64: 64Mb         128/123/12A*: 128Mb         256/253*: 256Mb       3: Byte Mode data output sequence.         512/513*: 512Mb       A: with 90 Degree shifted SCLK2.         16: 16b       26: 26b         * Density & Mode:       1000000000000000000000000000000000000	1 8V 8 1/0 Read-while-W/ri	te Serial NOR Elash	Def	Fault Maximum Dummy Cycle
Building       Building <td< td=""><td>251W/661W :</td><td></td><td>X: 1 C</td><td>S#, Default Standard I/O, Default 8 Dummy Cycles</td></td<>	251W/661W :		X: 1 C	S#, Default Standard I/O, Default 8 Dummy Cycles
<ul> <li>DENSITY:</li> <li>64: 64Mb</li> <li>128/123/12A*: 128Mb</li> <li>256/253*: 256Mb</li> <li>3: Byte Mode data output sequence.</li> <li>5: 12/513*: 512Mb</li> <li>A: with 90 Degree shifted SCLK2.</li> <li>16: 16b</li> <li>26: 26b</li> <li>* Density &amp; Mode:</li> <li>12A45: 128Mb with 90 Degree.</li> <li>shifted SCLK2</li> <li>63/123/253/513/163/263:</li> <li>Byte Mode data</li> <li>MODE:</li> <li>5: MXSMIO*Duplex(DTR)-Multi-in, Multi-out</li> <li>5: MULTI-OUT</li> <li>6: MXSMIO*Duplex(DTR)-Multi-in, Multi</li></ul>	3V. 8 I/O. Read-while-Write	Serial NOR Flash		FFATURE CODE 2:
DENSITY:       13: HOLD#, Default 3 Byte         64: 64Mb       25/237*: 256Mb       3: Byte Mode data output sequence.         512/513*: 512Mb       A: with 90 Degree shifted SCLK2.       6         1G: 1Gb       6: Cob       NODE:         12A45: 128Mb with 90 Degree shifted SCLK2.       63/23/253/513/163/263:       Byte Mode data         12A45: 128Mb with 90 Degree shifted SCLK2.       63/123/253/513/163/263:       Byte Mode data         12A45: 128Mb with 90 Degree shifted SCLK2.       5: MXSMIO®Duplex(DTR)-Multi-in, Multi-out       5: MXSMIO®-Security RPMC type         59: MXSMIO®-Security RPMC type       MODE:       S: MXSMIO®-Security RPMC type         GENERATION       GENERATION       U: Automotive Extended Grade 1 (-40°C to 135°C)			0/2· B	ESET# Default 3 Byte
4/6: RESET#, Permanent 4 Byte 128/123/12A* : 128Mb 256/253* : 256Mb 3 : Byte Mode data output sequence. 512/513* : 512Mb A : with 90 Degree shifted SCLK2. 1G : 1Gb 2G : 2Gb * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Descurity RPMC type * Descurity RPMC type	DENSITY:		1/3: H	IOLD#, Default 3 Byte
128/123/124*: 128Mb 256/253*: 256Mb 3: Byte Mode data output sequence. 512/513*: 512Mb A: with 90 Degree shifted SCLK2. 16: 1Gb 26: 2Gb * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3: Byte Mode data * Density & MODE: 45: MXSMIO*Duplex(DTR)-Multi-in, Multi-out 50: MXSMIO*-Security RPMC type * GENERATION * GENERATION * GENERATION	64 : 64Mb		4/6: R	ESET#, Permanent 4 Byte
256/253*: 256Mb 3: Byte Mode data output sequence. 512/513*: 512Mb A: with 90 Degree shifted SCLK2. 16: 16b 26: 26b * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/163/263: Byte Mode data	128/123/12A* : 128Mb		5/7: H	IOLD#, Permanent 4 Byte
<ul> <li>512/513*: 512Mb A: with 90 Degree shifted SCLK2.</li> <li>1G: 1Gb</li> <li>2G: 2Gb</li> <li>* Density &amp; Mode:</li> <li>12A45: 128Mb with 90 Degree shifted SDLK2.</li> <li>MDDE:</li> <li>45: MXSMI0*Duplex(DTR)-Multi-in, Multi-out</li> <li>50: MXSMIO*-Security RPMC type</li> <li>At Summary Control of the standard stand</li></ul>	256/253*: 256Mb 3: Byte	Mode data output sequence.		
1G : 1Gb 2G : 2Gb * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 63/123/253/513/1G3/2G3 : Byte Mode data	512/513* : 512Mb A : with	90 Degree shifted SCLK2.		- TEMPERATURE RANGE:
2G : 2Gb * Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 G3/123/253/513/1G3/2G3 : Byte Mode data MODE: 45 : MXSMIO®Duplex(DTR)-Multi-in, Multi-out 50 : MXSMIO®-Security RPMC type GENERATION ADDE: 45 : MXSMIO®-Security RPMC type ADDE: 45 : MXSMIO®-Security RPMC type	1G : 1Gb		1.50	I : Industrial (-40°C to 85°C)
* Density & Mode: 12A45: 128Mb with 90 Degree shifted SCLK2 G3/123/253/513/1G3/2G3: Byte Mode data MODE: 45 : MXSMIO®Duplex(DTR)-Multi-in, Multi-out 50 : MXSMIO®-Security RPMC type GENERATION M/M2: SOP XD/XR: BGA ZN/Z2/Z4 : WSON R : Automotive Grade 2 (-40°C to 105°C) S : Automotive Grade 3 (-40°C to 85°C) U : Automotive Extended Grade 1 (-40°C to 135°C)	2G : 2Gb	100 million (1997)	PACKAGE TYPE:	Q : Automotive Grade 1 (-40°C to 125°C)
12A45: 128Mb with 90 Degree shifted SCLK2 G3/123/253/513/1G3/2G3 : Byte Mode data 45 : MXSMIO®Duplex(DTR)-Multi-in, Multi-out 50 : MXSMIO®-Security RPMC type 5 : Automotive Grade 3 (-40°C to 85°C) U : Automotive Extended Grade 1 (-40°C to 135°C) GENERATION	* Density & Mode:	MODE:	M/M2: SOP	R : Automotive Grade 2 (-40°C to 105°C)
Shifted SLIZZ G3/123/253/513/1G3/2G3 : Byte Mode data D : MXSMIO®-Security RPMC type GENERATION	12A45: 128Mb with 90 Degree	45 : MXSMIO <sup>®</sup> Duplex(DTR)-Multi-in,	XD/XR: BGA	S : Automotive Grade 3 (-40°C to 85°C)
Byte Mode data 50 : MXSMIO®-Security RPMC type	snifted SCLK2 63/123/253/513/163/263 ·	Multi-out	ZN/Z2/Z4 : WSON	U : Automotive Extended Grade I (-40 C to 135 C)
GENERATION	Byte Mode data	50 : MXSMIO <sup>®</sup> -Security RPMC type		
GENERATION		3 - Benedictor		
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# NAND Flash

Macronix's broad NAND product portfolio covers a wide range of customer requirements, including both single-level cell(SLC) NAND and Serial NAND designed for a variety of demanding applications.

## **SLC NAND Flash**

Macronix SLC NAND complements its world-leading Serial and Parallel NOR Flash offerings. Our rigorous quality management system ensures that Macronix SLC NAND is one of the most robust and reliable NAND devices in the market.

Macronix focuses on the low density NAND market with industry-standard packages and features. The SLC NAND product portfolio includes: MX30LF/MX60LF family of 3V parallel SLC NAND ranging in densities from 1Gb to 8Gb; MX30UF family of 1.8V SLC NAND, offered in densities from 1Gb to 8Gb.

Density	ONFI	Cell Type	Bus Width	ECC Requirement	Speed (ns)	Voltage	Package	Automotive Grade				
MX30/	MX30/60LF 3V SLC NAND Flash											
8Gb	ONFI1.0	SLC	x8	4-bit, 8-bit ECC	20	2.7-3.6V	48-TSOP, 63-VFBGA	-40°C to 85°C -40°C to 105°C				
4Gb	ONFI1.0	SLC	x8	4-bit, 8-bit ECC	20	2.7-3.6V	48-TSOP, 63-VFBGA	-40°C to 85°C -40°C to 105°C				
2Gb	ONFI1.0	SLC	x8	4-bit, 8-bit ECC	20	2.7-3.6V	48-TSOP, 63-VFBGA	-40°C to 85°C -40°C to 105°C				
1Gb	ONFI1.0	SLC	x8	ECC-free, 4-bit ECC, 8-bit ECC	20	2.7-3.6V	48-TSOP/VFBGA, 63-VFBGA	-40°C to 105°C				
MX30/	60UF 1.8	/ SLC NA	ND Flash	1								
8Gb	ONFI1.0	SLC	x8	4-bit, 8-bit ECC	25	1.7V-1.95V	48-TSOP, 63-VFBGA	-40°C to 105°C				
4Gb	ONFI1.0	SLC	x8,x16	4-bit, 8-bit ECC	25	1.7V-1.95V	48-TSOP, 63-VFBGA	-40°C to 105°C				
2Gb	ONFI1.0	SLC	x8,x16	4-bit, 8-bit ECC	25	1.7V-1.95V	48-TSOP/VFBGA, 63-VFBGA	-40°C to 105°C				
1Gb	ONFI1.0	SLC	x8,x16	4-bit, 8-bit ECC	25	1.7V-1.95V	48-TSOP/VFBGA, 63-VFBGA	-40°C to 105°C				

Note: For more NAND related information, please contact Macronix sales.

### Serial NAND Flash

As embedded systems evolve, there are many applications with a Serial Peripheral Interface (SPI) that require higher-density memory solutions to store large image files. Recognizing such application needs, Macronix, as a global leader in Serial Flash memory, offers a new MX35 Serial NAND family for a NAND-based storage solution.

The MX35 family provides storage capacity from 1Gb to 4Gb densities with a low cost-per-megabit, and as such, Macronix Serial NAND is ideal for embedded applications such as digital TVs, set-top boxes, and AP routers as these applications now contain more sophisticated operating systems for managing multimedia, photos and other data intensive content.

Macronix Serial NAND is compatible with the industry standard Serial Peripheral Interface (SPI) command set, allowing designers to easily and cost-effectively expand their application storage capacity without having to perform a complete system redesign and hence achieve short time-to-market, realizing the benefits of using Macronix Serial NAND.

Density	Interface	Cell Type	Bus Width	ECC Requirement	Speed (ns)	Voltage	Package	Temperature Range			
MX35	MX35LF 3V Serial NAND Flash										
4Gb	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	120	2.7V-3.6V	8-WSON	Industrial Grade (I) -40°C to +85°C			
	SPI Quad Output	SLC	x1, x2, x4	ECC-free	104	2.7-3.6V	8-WSON	Automotive Grade (R) -40°C to +105°C			
ach	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	120	2.7-3.6V	8-WSON	Industrial Grade (I) -40°C to +85°C			
ZGD	SPI Quad Output	SLC	x1, x2, x4	4-bit ECC, ECC-free	104	2.7-3.6V	8-WSON, 16-SOP	Automotive Grade (R) -40°C to +105°C			
1Ch	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	120	2.7-3.6V	8-WSON	Industrial Grade (I) -40°C to +85°C			
100	SPI Quad Output	SLC	x1, x2, x4	ECC-free	104	2.7-3.6V	8-WSON	Automotive Grade (R) -40°C to +105°C			
MX35	UF 1.8V Serial N	AND F	lash								
ACh	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	166	1.7V-1.95V	8-WSON	Industrial Grade (I)			
460	SPI Quad Output	SLC	x1, x2, x4	ECC-free	133	1.7V-1.95V	8-WSON	-40°C to +85°C			
	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	166	1.7V-1.95V	8-WSON				
2Gb	SPI Quad Output	SLC	x1, x2, x4	ECC-free	133	1.7V-1.95V	8-WSON	Industrial Grade (I) -40°C to +85°C			
	SPI Quad Output	SLC	x1, x2, x4	4-bit ECC, ECC-free	104	1.7V-1.95V	8-WSON, 24-BGA (5x5 ball array)				
	SPI Quad Output	SLC	x1, x2, x4	8-bit ECC	166	1.7V-1.95V	8-WSON				
1Gb	SPI Quad Output	SLC	x1, x2, x4	ECC-free	133	1.7V-1.95V	8-WSON	Industrial Grade (I) -40°C to +85°C			
	SPI Quad Output	SLC	x1, x2, x4	4-bit ECC, ECC-free	104	1.7V-1.95V	8-WSON, 24-BGA (5x5 ball array)				



# e.MMC<sup>™</sup>Memory

As a leader in the non-volatile memory market, Macronix has launched a family of e.MMC<sup>™</sup> memory to meet the needs of high capacity storage and high reliability applications. This memory offering from Macronix is made possible by combining years of experience in the design and management of Flash memory with its advanced in-house NAND Flash fabrication technologies.

With profound experience in embedded solutions, Macronix is able to develop the optimized management firmware to provide a longer product lifespan with robust data integrity. This managed Flash solution optimizes memory mapping, bad block management, wear-leveling, and error correction techniques to fulfill the higher reliability demands required by developers. To face the challenges of demanding application environments, Macronix's e.MMC<sup>™</sup> memory can help developers increase system availability and reduce maintenance efforts.

Macronix integrates its MLC NAND Flash and controller in a BGA package with a standard interface to the host system. The e.MMC<sup>™</sup> memory is ideal for various applications, such as digital TV, set-top boxes, infotainment, industrial and networking applications. It is also available in the 11x10mm BGA package for wearable applications.

Density	Voltage (VCC)	Cell Type	<i>e</i> .MMC Version	Bus Width	Max. Bandwidth (MB/s)	Package	Temperature Range
MX52L e.MMC <sup>™</sup> Flash Memory							
8GB	2.7V-3.6V	MLC	5.1	x1, x4, x8	400	11.5x13mm 153-FBGA 11x10mm 153-FBGA	-40°C to +85°C
4GB	2.7V-3.6V	MLC	5.1	x1, x4, x8	400	11.5x13mm 153-FBGA 11x10mm 153-FBGA	-40°C to +85°C
2GB	2.7V-3.6V	MLC	5.1	x1, x4, x8	400	11x10mm 153-FBGA	-40°C to +85°C

Note: *e*.MMC<sup>™</sup> is the trademark of JEDEC/MMCA.





# **ArmorFlash**<sup>™</sup>

As more devices connect to the Internet, these networks are becoming more sophisticated with valuable data to protect. There are increasing concerns regarding the vulnerability of these growing networks to outside influences and potential exposure to a myriad of data that needs to be secure.

ArmorFlash<sup>™</sup> supports a standard SPI, QSPI, and OctaBus Interface which is based on highly configurable security technologies providing a secure ID, authentication, and an encrypted link for NOR, SLC NAND, or e.MMC<sup>™</sup> Flash.

The data encrypted by ArmorFlash<sup>™</sup> uses a security protocol that provides unique transfers even when repeatedly reading the same address of the ArmorFlash<sup>™</sup> secure memory region. ArmorFlash<sup>™</sup> offers high levels of data confidentiality, integrity and availability to prevent data from being compromised. This storage is also offered in a number of densities to meet your application's needs.

ArmorFlash<sup>™</sup> offers secure technologies like a Physical Unclonable Function (PUF) that makes use of a semiconductor's biometrics, which are characteristics derived from fabrication that can be used for encoding or identification. This highly unique fingerprint cannot be predicted, duplicated, or cloned and so provides a reliable unique ID with very high levels of entropy.

ArmorFlash<sup>™</sup> is an ideal security solution for a wide range of identification, authentication and encryption requirements for IoT, automotive, computing, industrial, healthcare, wearables, smart home, and smart cities.

### **Key Features**

- Standard SPI/QSPI/OctaBus Interface
- Non-volatile Monotonic Counters

• AEC-Q100 Grade-1/2/3 Compliant

- True Random Number Generator (TRNG)
- Physical Unclonable Functions (PUF) Support

### **Automotive Grade**

- Hardware Crypto Engines
- Symmetric and Asymmetric Key Provision and Management
- Secure Areas for Authentication/Encryption/Decryption
- Standard Areas for Authentication

### **Security Certifications**

• NIST CAVP Validated

### Serial NOR Flash

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Density	Status	Voltage (VCC)	Security Features	Frequency, MHz (Bus Width)	Package	Temperature Range				
MX75L25690F										
256Mb	Production	2.7V-3.6V	Standard Serial NOR Interface PUF Secured OTP Unique ID AES Engine TRNG Monotonic Counter	120(x1, x2) 104(x4)	300mil 16-SOP	Industrial Grade -40°C to +85°C				
MX75	U25690F				·					
256Mb	Production	1.65V-2.0V	Standard Serial NOR Interface PUF Secured OTP Unique ID AES Engine TRNG Monotonic Counter	120(x1, x2) 104(x4)	6x8mm 24-TFBGA(5x5)	Industrial Grade -40°C to +85°C Automotive Grade -40°C to +105°C				

Serial											
Density	Status	Voltage (VCC)	Security Features	Frequency, MHz (Bus Width)	Package	Temperature Range					
MX78	MX78L64A00F										
64Mb	Under Development	2.7V-3.6V	Standard Serial NOR Interface AES/ECC/SHA Hardware Engine TRNG Unique ID PUF Monotonic Counter	133(x1) 120(x2) 104(x4)	6x8mm 24-TFBGA(5x5)	Automotive Grade -40°C to +105°C					
MX78	U64A00F										
64Mb	Sampling	1.65V-2.0V	Standard Serial NOR Interface AES/ECC/SHA Hardware Engine TRNG Unique ID PUF Monotonic Counter	133(x1) 120(x2) 104(x4)	6x8mm 24-TFBGA(5x5)	Automotive Grade -40°C to +105°C					
MX76	MX76U3233F										
32Mb	Production	1.65V-2.0V	Standard Serial NOR Interface PUF Secured OTP Unique ID	80 (x1, x2, x4)	200mil 8-SOP	Industrial Grade -40°C to +85°C					

Note: *e*•MMC<sup>™</sup> is the trademark of JEDEC/MMCA.



# LybraFlash<sup>™</sup>

### LybraFlash<sup>™</sup> : The Optimum Solution for Gigabit Flash Memory

Today's applications continue to quickly evolve to support growing demands from the markets they serve. This demand is lengthening feature lists and driving the growth of non-volatile memory (NVM) capacities, previously 32-64MB, jumping to 128MB and above. These trends are also compelling the adoption of NAND Flash over NOR Flash for the cost advantage, when the density range of NOR can be matched by NAND. However, it can be an initial undertaking to work with NAND if the system designer lacks experience in doing so or if the application hardware doesn't support it.

Please contact Macronix sales for more details.

With that challenge in mind, Macronix has developed LybraFlash<sup>™</sup> as an ideal choice for most automotive systems. LybraFlash<sup>™</sup> delivers a user experience comparable to NOR flash, with no need to change the system's hardware design and only small modifications to system software to achieve this.

LybraFlash<sup>™</sup> implements an embedded ECC engine to deliver high integrity data. This feature paves the way for most MCU platforms lacking either support of ECC hardware or computing power based on software ECC calculations. In order to achieve the highest data integrity possible, LybraFlash<sup>™</sup> also provides other enhanced reliability features that provide impressive data reliability performance.

LybraFlash<sup>™</sup> Memory is a great fit for code storage use, accomplished by high performance continuous read operation, fast write (program/erase) performance, strong data integrity, and respectable endurance.

For those that want fast write performance, similar read performance compared to standard SPI NOR Flash, and cost effective high capacity Flash memory, LybraFlash™ could be the right solution for that next project.

# **Key Features**

- Solution Coverage of the MX31 Series:
- VCC: 3V family (MX31LFxGE4BC) & 1.8V family (MX31UFxGE4BC)
- Density: 1Gb and 2Gb
- Interface: SPI Single, Dual, Quad I/O(1-1-1, 1-1-2, 1-1-4, 1-2-2, 1-4-4)
- High Performance
- Read throughput: ~50MB/s (Quad I/O, w/ continuous read mode)
- SPI clock rate: 104MHz Quad I/O
- Special Features for NOR-like Boot Applications: Please contact Macronix for details
- High Reliability Features: (please contact Macronix for details)
- Package: 8-WSON, 24-BGA, 16-SOP



Density	Voltage	Read Speed (MHz)	Page Size	Enhanced Reliability Features	NOR-like booting	P/E Cycles	Package	Temperature Range		
MX31LF 3V LybraFlash R-Grade (-40°C to 105°C)										
1GB	2.7V-3.6V	104	2KB	٠	٠	100K	8-WSON, 24-BGA, 16-SOP	I-Grade (-40° <b>C to 85°C)</b> R-Grade (-40° <b>C to 105°C)</b>		
2GB	2.7V-3.6V	104	2KB	•	•	100K	8-WSON, 24-BGA, 16-SOP	R-Grade (-40 <b>°C to 85°C)</b>		
MX31U	JF 1.8V Lyk	oraFlash R-(	Grade (-4	0°C to 105	°C)					
1GB	1.7V-1.95V	104	2КВ	٠	٠	100K	8-WSON, 24-BGA, 16-SOP	R-Grade (-40 <b>°C to 85°C)</b>		
2GB	1.7V-1.95V	104	2KB	•	•	100K	8-WSON, 24-BGA, 16-SOP	R-Grade (-40° <b>C to 85°C)</b>		



# Secure Flash

Nowadays, security is at the forefront of many applications. Several Flash memory products are now equipped with various security features. Macronix provides an expansive product portfolio of security solutions, which enable customers to protect confidential/sensitive and private data stored in Flash memory from malicious overwrites and attacks.

The Macronix Secure Flash portfolio includes a broad offering of NOR memories: Parallel NOR available in densities from 16Mb to 1Gb, Serial NOR 16Mb to 1Gb. Macronix Secure NAND Flash, the MX30LFxxS series, provides the advanced PBL (Permanently Block Lock) security feature implemented in the NAND device. This security feature could permanently set block or sector of a flash to be read only, which protects the confidential code from intentional tampering and attacks. The products are available in densities from 1Gb to 4Gb and support ONFI 1.0 NAND interface.

Secure Flash is primarily used for the applications that require data and code security, such as the Set-Top Box, Digital TV, etc.

Density	Organization	I/O Bus	Speed (MHz)	Voltage	Mode	Package
MX25	66L 3V Seria	I NOR Flash				
1Gb	4KB/32KB/64KB	x1,x2,x4	166	2.7-3.6V	Multi I/O	16-SOP, 24-TFBGA
512Mb	4KB/32KB/64KB	x1,x2,x4	166	2.7-3.6V	Multi I/O	16-SOP, 24-TFBGA
256Mb	4KB/32KB/64KB	x1,x2,x4	133	2.7-3.6V	Multi I/O	16-SOP, 24-TFBGA
	4KB/32KB/64KB	x1,x2,x4	133	2.7-3.6V	Multi I/O	16-SOP, 24-TFBGA
UIVI821	4KB/32KB/64KB	x1,x2,x4	84	2.7-3.6V	Multi I/O, RPMC Mode	8-PDIP/SOP/WSON
GANAb	4KB/32KB/64KB	x1,x2,x4	120	2.7-3.6V	Multi I/O	8-SOP, 16-SOP, 24-TFBGA
041010	4KB/32KB/64KB	x1,x2,x4	84	2.7-3.6V	Multi I/O, RPMC Mode	8-PDIP/SOP/WSON
32Mb	4KB/32KB/64KB	x1,x2,x4	104	2.7-3.6V	Multi I/O	8-SOP, 24-TFBGA
16Mb	4KB/64KB	x1,x2,x4	104	2.7-3.6V	Multi I/O	8-SOP, 24-TFBGA

### Serial Secure NOR Flash

# Parallel Secure NOR Flash

11100

Density	Bus Width	Speed (ns)	Voltage	Feature	Package					
MX29	LA 3V Parallel	NOR Flash								
64Mb	x8, x16	70	2.7-3.6V	Uniform Sector	64-FBGA					
32Mb	x8, x16	70	2.7-3.6V	Uniform Sector	64-FBGA					
MX29/68GA 3V Parallel NOR Flash										
1Gb	x8, x16	110	2.7-3.6V	Page Mode, Uniform Sector	64-FBGA					
512Mb	x8, x16	100	2.7-3.6V	Page Mode, Uniform Sector	64-LFBGA					
256Mb	x8, x16	90	2.7-3.6V	Page Mode, Uniform Sector	64-FBGA / LFBGA					
128Mb	x8, x16	90	2.7-3.6V	Page Mode, Uniform Sector	64-FBGA / LFBGA					
64Mb	x8, x16	90	2.7-3.6V	Page Mode, Uniform Sector	64-FBGA / LFBGA					
32Mb	x8, x16	70	2.7-3.6V	Page Mode, Uniform Sector	64-FBGA / LFBGA					

# Secure SLC NAND Flash

Density	Cell Type	Bus Width	ECC Requirement	Speed (ns)	Voltage	Feature	Package			
MX30LF 3V SLC NAND Flash										
4Gb	SLC	x8	4-bit ECC	20	2.7-3.6V	PBL (Permanently Block-Locked)	63-VFBGA			
2Gb	SLC	x8	4-bit ECC, 8-bit ECC	20	2.7-3.6V	PBL (Permanently Block-Locked)	63-VFBGA			
1Gb	SLC	x8	4-bit ECC, 8-bit ECC	20	2.7-3.6V	PBL (Permanently Block-Locked)	63-VFBGA			



# MCP (Multichip Packages)

Macronix is especially leading the 1.8V/3V Flash memory specification for power saving and space constraint needs. Made by state-of-art manufacturing capability and quality controls, our MCP solution portfolio provides flexible choices and fast time-to-market advantages for both embedded and wireless application usage. With a small footprint and backward compatible pinout, customers can choose different densities to meet their cost effective solutions.

### **NOR-Based MCP**

NOR Density	NOR Product Type	NOR Bus Width	OctaRAM Density	pSRAM Bus Width	Voltage	Package Type	Temperature Range			
MX65L 3V MCP NOR Flash										
512Mb	octaflash	x1, x8	64Mb	x1, x8	3V	24-BGA	-40°C to +85°C -40°C to +105°C			

NOR Density	NOR Product Type	NOR Bus Width	pSRAM Density	pSRAM Bus Width	Voltage	Package Type	Temperature Range		
MX69GL 3V Parallel NOR-Based MCP									
64Mb	De-Mux	x16	32Mb	x16	3V	5 <mark>6-TFBGA</mark>	-40°C to +85°C		
MX69V 1.8V Parallel NOR-Based MCP									
128Mb	AD-Mux	x16	64Mb	x16	1.8V	56-TFBGA	-25°C to +85°C		
MX69N 1.8V Parallel NOR-Based MCP									
64Mb	AD-Mux	x16	32Mb	x16	1.8V	52-TFBGA, 56-TFBGA	-25°C to +85°C -40°C to +85°C		

NOR Density	NAND Product Type	NAND Bus Width	LPDDR Density	LPDDR Product Type	LPDDR Bus Width	Voltage	ECC Requirement	Package Type	Temperature Range
MX63U 1.8V NAND-Based MCP									
4Gb	ONFI	x8	2Gb	LPDDR2	x16, x32	1.8V	4-bit, 8-bit ECC	162-TFBGA	-30°C to +85°C -40°C to +85°C
2Gb	ONFI	x8,x16	2Gb,1Gb	LPDDR2	x16, x32	1.8V	4-bit, 8-bit ECC	162-TFBGA	-30°C to +85°C -40°C to +85°C
1Gb	ONFI	x8,x16	1Gb, 512Mb	LPDDR2	x16, x32	1.8V	4-bit ECC	162-TFBGA	-30°C to +85°C -40°C to +85°C



# Parallel NOR Flash

Macronix offers an extensive line of 3V, 1.8V and 5V industry standard Parallel NOR Flash memory products from 2Mb to 1Gb densities.

These products feature Boot and Uniform Sector architectures in x8, x16, and x8/x16 selectable configurations. Macronix NOR Flash memory provides customers with cost-effective, high performance and reliable products that offer low-power consumption, high endurance and reliability.

### **Standard Read Access**

Density	Bus Width	Speed (ns)	Package	Feature	Voltage	Automotive Grade
MX29	F 5V Par	allel NO	R Flash			
8Mb	x8, x16	70	44-SOP, 48-TSOP/LFBGA	Boot Sector	4.5-5.5V	
4Mb	x8, x16	70	32-PLCC/TSOP, 44-SOP, 48-TSOP	Uniform Sector, Boot Sector	4.5-5.5V	-40°C to +105°C
2Mb	x8, x16	70	44-SOP, 48-TSOP	Boot Sector	4.5-5.5V	
MX29	<b>9LV</b> 3V P	arallel N	IOR Flash			
64Mb	x8, x16	70	48-TSOP/LFBGA	Boot Sector	2.7-3.6V	-40°C to +105°C
32Mb	x8, x16	70	44-SOP, 48-TSOP/TFBGA/LFBGA	Boot Sector, V I/O=1.8V	2.7-3.6V	-40°C to +105°C
16Mb	x8, x16	70	48-TSOP/WFBGA/TFBGA/LFBGA/ XFLGA	Boot Sector, V I/O=1.8V	2.7-3.6V	-40°C to +85°C
8Mb	x8, x16	70	44-SOP, 48-TSOP/WFBGA/TFBGA/ LFBGA/XFLGA	Boot Sector	2.7-3.6V	-40°C to +105°C
4Mb	x8, x16	70	32-PLCC/TSOP, 44-SOP, 48-TSOP/ WFBGA/TFBGA/LFBGA/XFLGA	Uniform Sector, Boot Sector	2.7-3.6V	
MX29	<b>SL</b> 1.8V	Parallel	NOR Flash			
8Mb	x8, x16	90	48-TSOP/WFBGA/TFBGA/LFBGA/ XFLGA	Boot Sector	1.65-2.2V	
4Mb	x8, x16	90	48-TSOP/WFBGA/TFBGA/LFBGA/ XFLGA	Boot Sector	1.65-2.2V	

### Page Mode Read Access

The GL family offers enhanced performance products with faster effective programming and read time, which makes GL family ideal for applications demanding for higher density, better performance and lower power consumption.

Density	Bus Width	Speed (ns)	Package	Feature	Voltage	Automotive Grade			
MX29/68GL 3V Paralle NOR Flash									
1Gb	x8, x16	100	56-TSOP, 64-LFBGA	V I/O, Uniform Sector	2.7-3.6V	-40°C to +105°C			
512Mb	x8, x16	100	56-TSOP/FBGA, 64-LFBGA	V I/O, Uniform Sector	2.7-3.6V	-40°C to +105°C			

Density	Bus Width	Speed (ns)	Package	Feature	Voltage	Automotive Grade			
MX29/68GL 3V Paralle NOR Flash									
256Mb	x8, x16	90	56-TSOP/FBGA, 64-FBGA/LFBGA, 70-SSOP	V I/O, Uniform Sector	2.7-3.6V	-40°C to +105°C			
128Mb	x8, x16	70	56-TSOP/FBGA, 64-FBGA/LFBGA, 70-SSOP	V I/O, Uniform Sector	2.7-3.6V	-40°C to +105°C			
64Mb	x8, x16	70	48-TSOP/LFBGA/TFBGA, 56-TSOP, 64-LFBGA	Uniform Sector, Boot Sector	2.7-3.6V	-40°C to +105°C			
32Mb	x8, x16	70	48-TSOP/LFBGA/TFBGA, 56-TSOP, 64-LFBGA	Uniform Sector, Boot Sector	2.7-3.6V	-40°C to +105°C			

Note: V I/O: Versatile power supply for Input/Output

### **Burst Mode Read Access**

The product families offer leading edge performance with 1.8V, Burst mode and Address-Data Multiplexing (AD-Mux). The MX29NS is a single-bank product, while the MX29VS offers multi-bank architecture for simultaneous read-write capability. With 1.8V operation, faster effective programming and burst read time, the families are ideal for applications demanding high performance and low power consumption.

Density	Bus Width	Speed (ns)	Package	Feature	Voltage	Automotive Grade					
MX29VS 1.8V Parallel NOR Flash											
128Mb	x16	80	56-TFBGA	AD-Mux; Burst Mode Read While Write	1.7-1.95V						
MX29NS 1.8V Parallel NOR Flash											
64Mb	x16	80	56-TFBGA	AD-Mux; Burst Mode	1.7-1.95V						
32Mb	x16	80	56-TFBGA	AD-Mux; Burst Mode	1.7-1.95V						



# KGD (Known Good Die)

Macronix provides Known Good Die products for custom System in Package (SiP) solutions requiring small form factor Flash memory.

Our KGD products are ideal for diverse applications, such as portable consumer electronics, set top box, DSC, mobile phones, IoT/wearable devices, automotive devices, GPS, tablets, industrial, networking....etc.

Macronix is will apply its stringent process for qualification, testing, extended temperature support and packaging to its line of KGD products, and committed to delivering:

• Stringent quality management to meet the requirements of most demanding applications, even the automotive segment.

• Professional service offered by our dedicated technical support team to support various customer needs.

• Effective production control & planning to ensure longevity supply and support

	Voltage	512Kb	1Mb	2Mb	4Mb	8Mb	16Mb	32Mb	64Mb	128Mb	256Mb	512Mb	1Gb	2Gb	4Gb
Serial NOR Flash															
MX25L	3V	•	•	•	•	•	•	•	•	•	•	•			
MX25V	2.5V	•	•	•	•	•	•	•*	•*						
MX25U	1.8V	•	•	•	•	•	•	•	•		•*	•			
MX25R	Ultra Low Power(1)	•	•	•	•	٠	•	•	•*						
Parallel NOR Flash															
MX29LV	3V				•	•	•	•	٠						
MX29GL	3V							•	•	•	•				
MX29SL	1.8V				•	•									
MX29NS	1.8V				_			•	•	•					
MX29VS	1.8V	.11								•					
SLC NAND Flash															
MX30LF	3V							- 5				•	•	•	•
MX30UF	1.8V								-				•	•*	

• Complete testing for function, data retention, endurance, etc.

\* Advance Information

Note: (1) Ultra Low Power/Wide Range Vcc. (1.65-3.6V)

# ROM (Read-Only Memory)

As the NO.1 ROM provider in the industry, we continue to offer the cutting-edge ROM products to our valued customers.

Migrating from Mask ROM to XtraROM<sup>®</sup> with significant resources investment, Macronix has made ROM products more flexible in production and delivery, while preserving high quality and cost advantages.

### ASIC XtraROM®

Macronix excels at customized XtraROM<sup>®</sup> from IC design to content programming to quick delivery. We can build your DRM (Digital Right Management) scheme in the circuit of XtraROM<sup>®</sup> to protect your content from being pirated. Our designs are used in handheld gaming consoles around the world.

MACRONIX Read Only Memory



# Packages

# Serial NOR Flash



The result package is subject to various die sizes. The smallest chip so far is 1.24x1.29mm.



**8-SOP (200mil)** 7.9x5.23x2.16mm, Pitch 1.27mm





# **8-USON 4**x4x0.6mm, Pitch 0.8mm









# **Multichip Packages**





**130 TFBGA** (Ball Dia.0.3) 8x9x1.0mm, Pitch 0.65mm



### **Parallel NOR Flash**











(Ball Dia. 0.4) 9x7x1.2mm, Pitch 0.8mm



**44-SOP (500mil)** 28.5x16.03x3mm, Pitch 1.27mm

MACRONIX



MACRONA

**56-TSOP** 20x14x1.2mm, Pitch 0.5mm



28.5x16.03x3.05mm,Pitch 0.8mm

### **NAND Flash**

**48-TSOP** 12x20x1.2mm, Pitch 0.5mm



63-VFBGA (Ball Dia.0.45) 9x11x1.0mm, Pitch 0.8mm





### e.MMC<sup>™</sup>





# Your Trustworthy & Reliable Partner for Flash Memory

# ii B

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Except for specially designed product, Macronix products shall not be used for applications relating to nuclear facility, military, life saving, life sustaining, aircraft, or systems where failure or malfunction may result in personal injury.